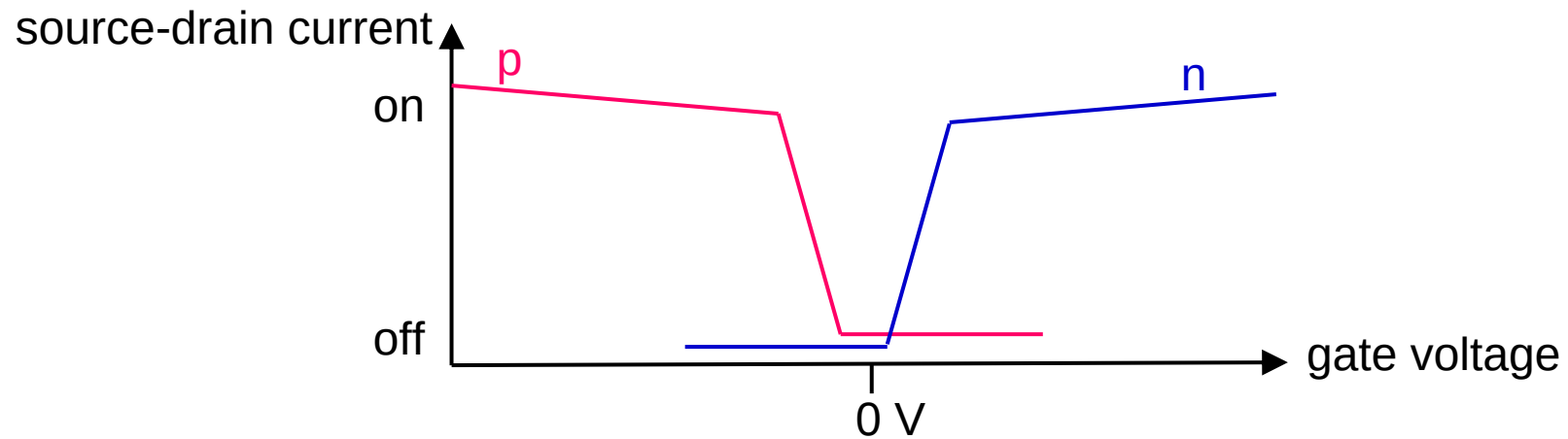
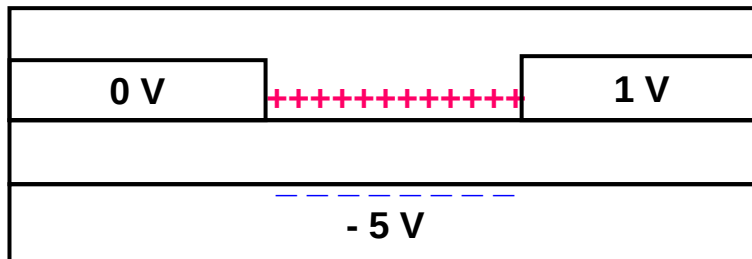


Recombination Zone Modeling in Organic Light Emitting Field Effect Transistors

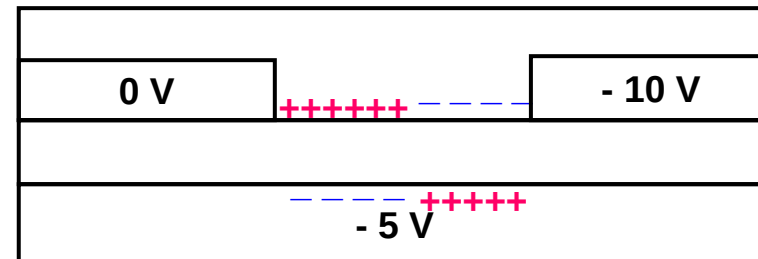
Organic Transistor



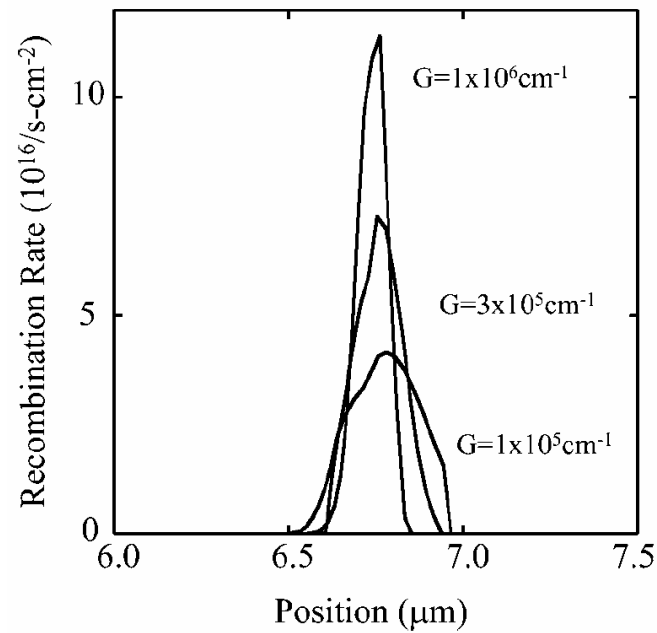
unipolar



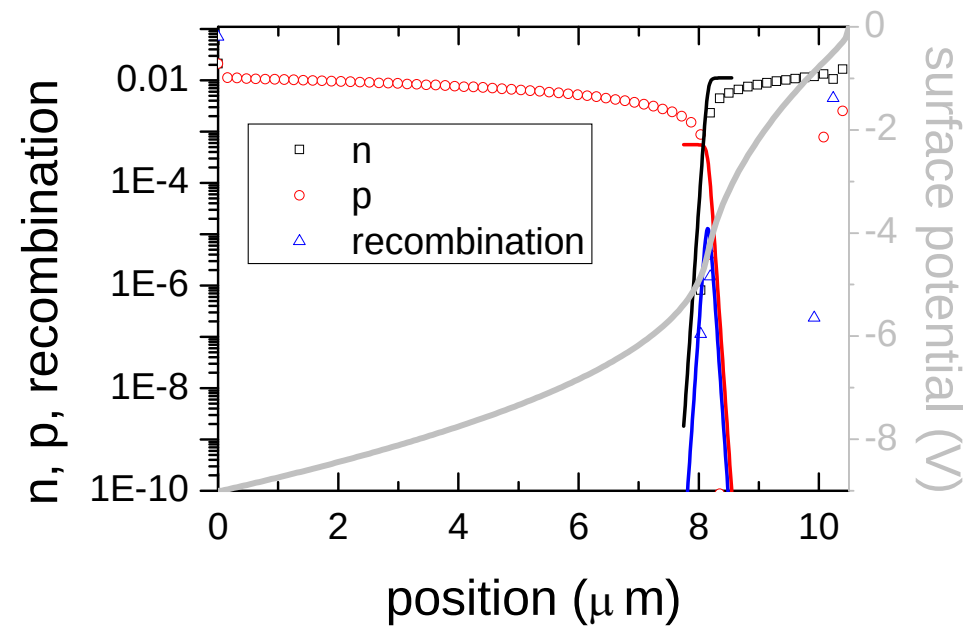
ambipolar



Theoretical Predictions



D.L. Smith *et al*, J. Appl. Phys. **101**, 084503 (2007)



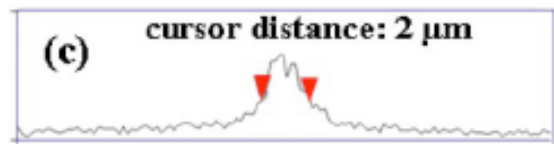
Numerical drift/diffusion model
vs. Analytical drift-only model
(recombination according to Langevin)

Martijn Kemerink

Full Width at Half Maximum FWHM $\sim 20 - 200 \text{ nm}$

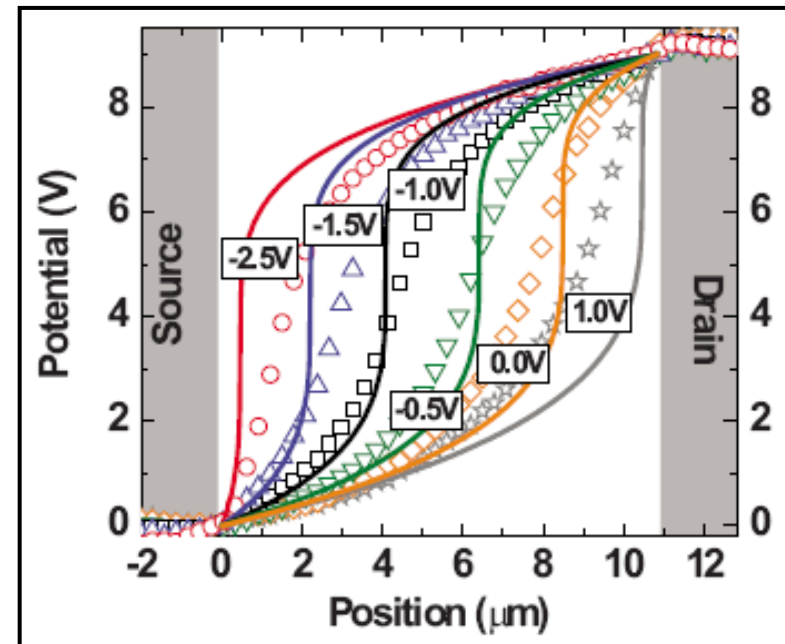
Experimental Results

Confocal microscope / High fields
PPV



J.S. Swensen *et al*, J. Appl. Phys. **102**, 013103 (2007)

Scanning Kelvin Probe Microscope
NiDT



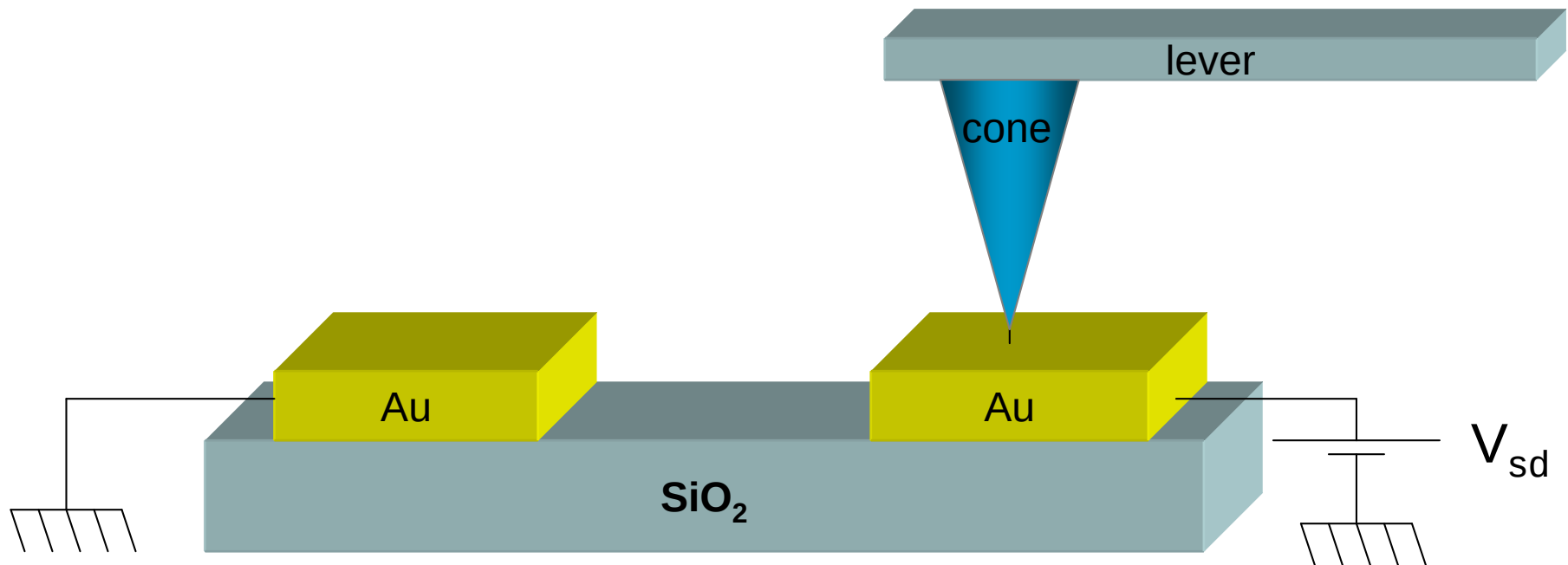
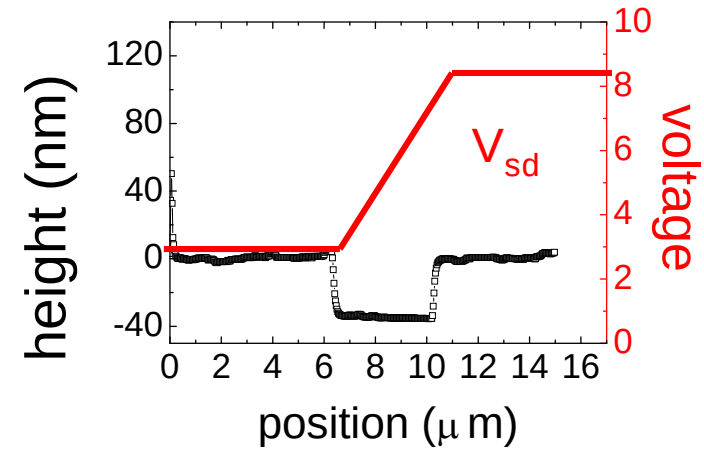
E.C.P. Smits *et al*, Phys. Rev. B **76**, 125202 (2007)

FWHM $\sim 2 \mu\text{m}$

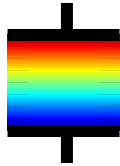
Scanning Kelvin Probe Microscope = SKPM

Interleave mode

- Atomic Force Microscope in tapping mode
- Surface potential at Lift Height Z_L



Principle: First Harmonic Force Microscope



$$F = -\frac{V^2}{2} \frac{dC}{dz}$$

F = force between tip and sample
V = tip-sample voltage difference
C = capacity between tip and sample

$$V = V_{dc} + V_{ac} \sin(\omega t) - V_{cpd}$$

V_{dc} = tip voltage

V_{ac} = amplitude voltage

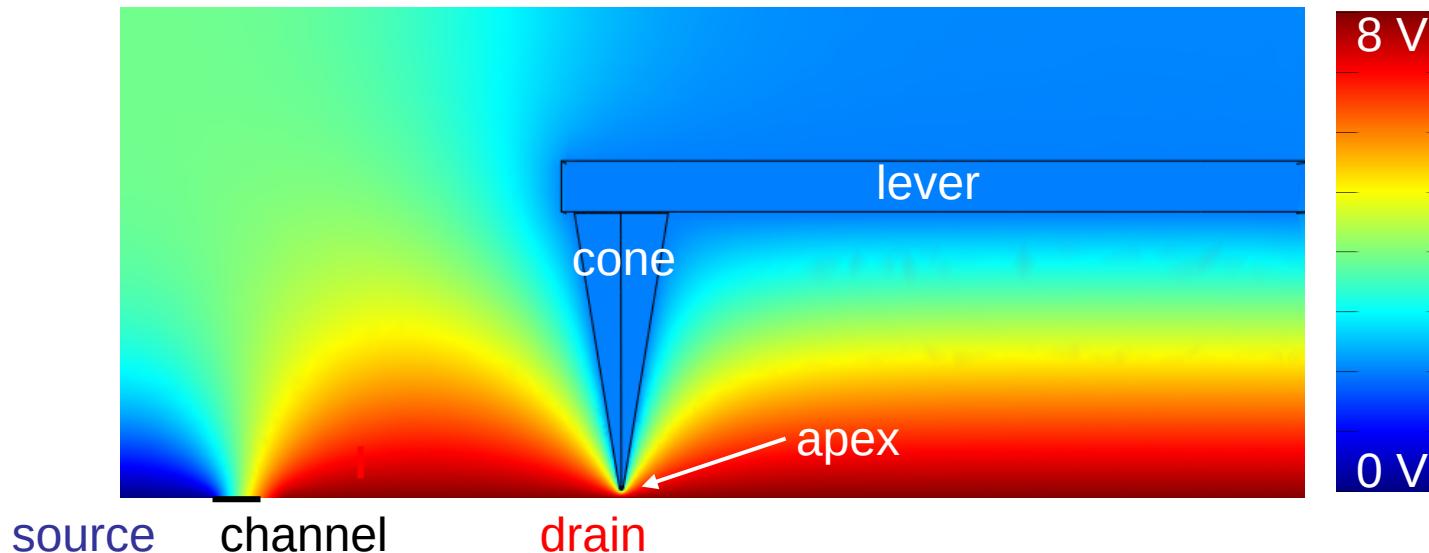
V_{cpd} = contact potential difference

$$F = F_{dc} + F_{\omega} \sin \omega t + F_{2\omega} \cos 2\omega t$$

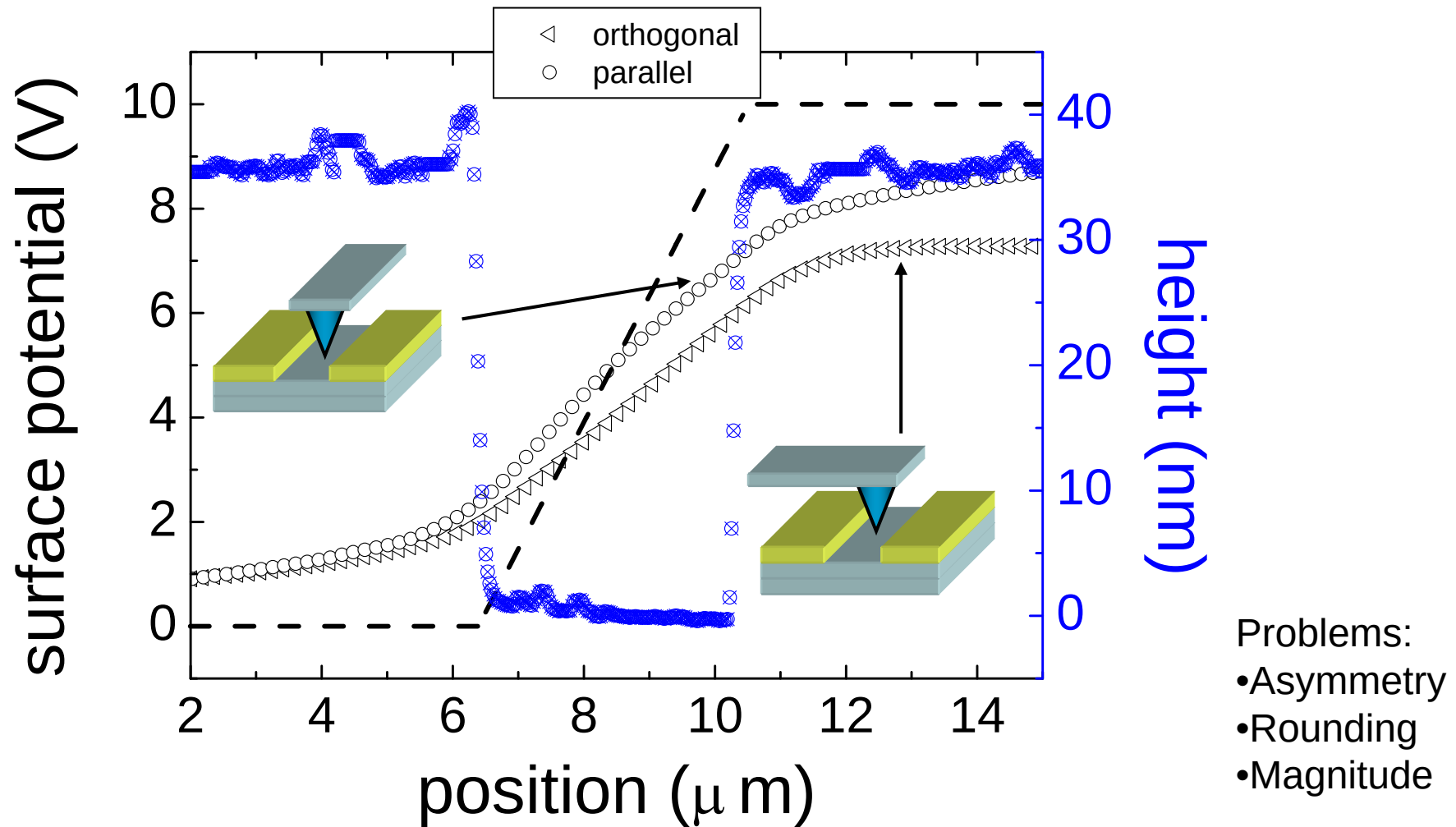


$$F_{\omega} = \frac{dC}{dz} V_{ac} (V_{cpd} - V_{dc})$$

Then $V_{cpd} = V_{dc}$
 For $F_{\omega} = 0$

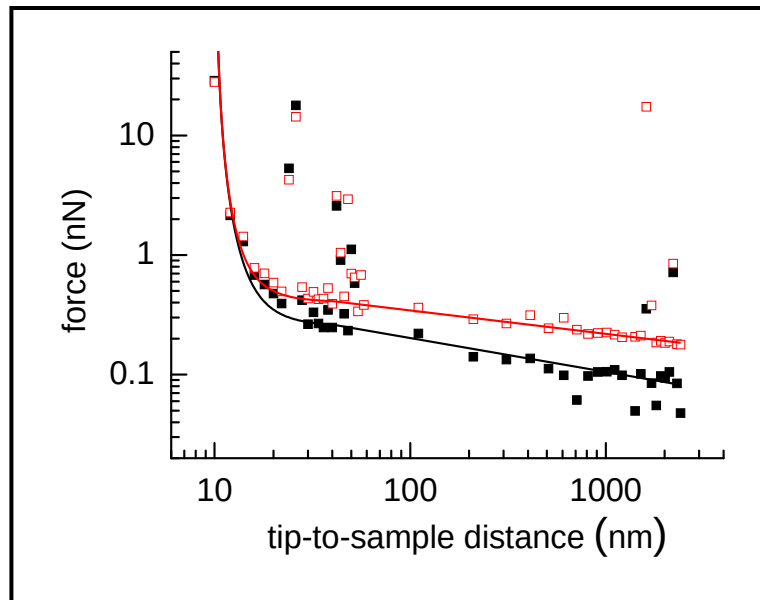
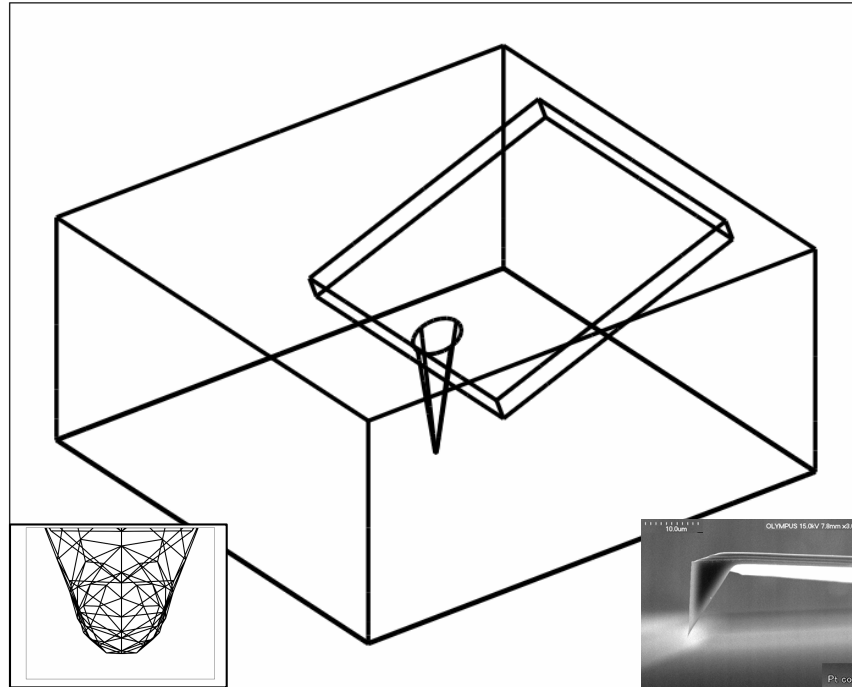


Instrumental Problem: SKPM Response

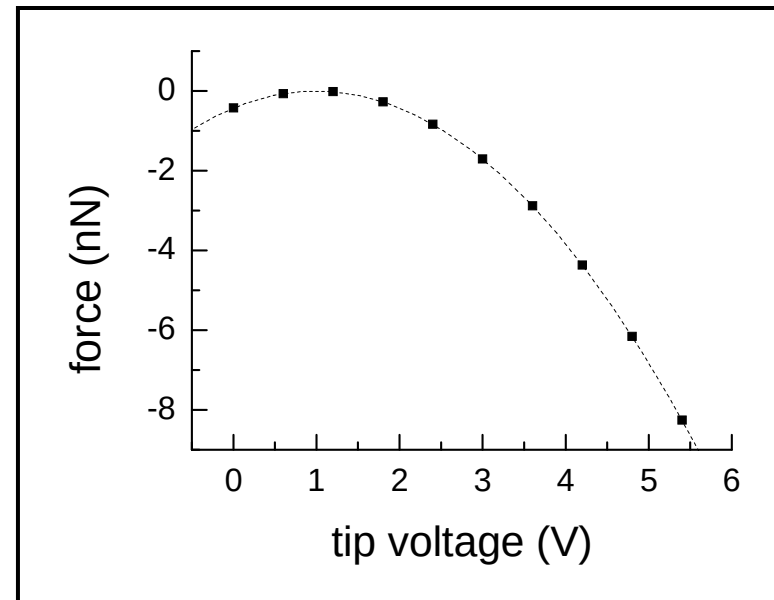


SKPM Response 3D Model

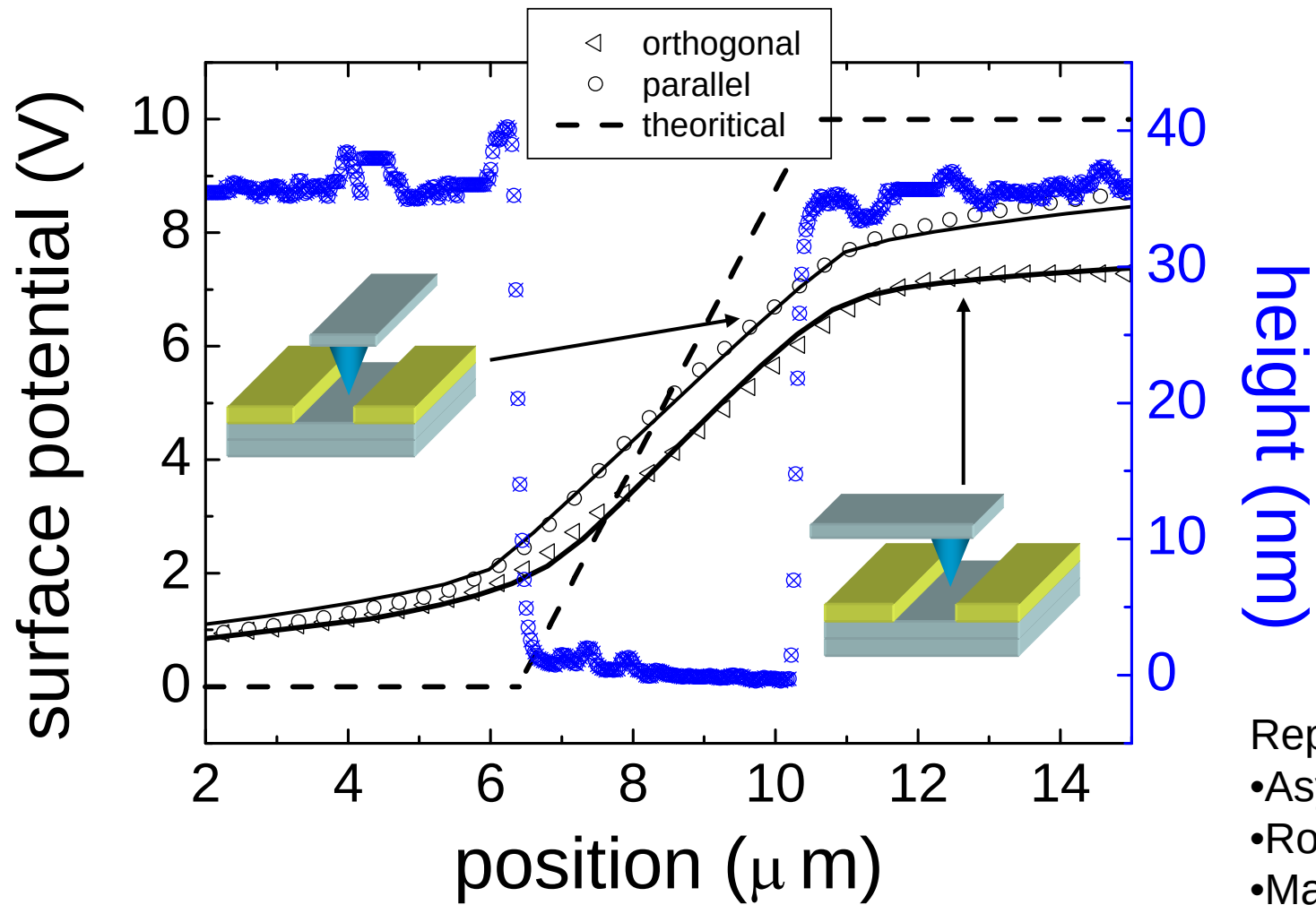
Simulated
with Finite Element Program
(COMSOL)



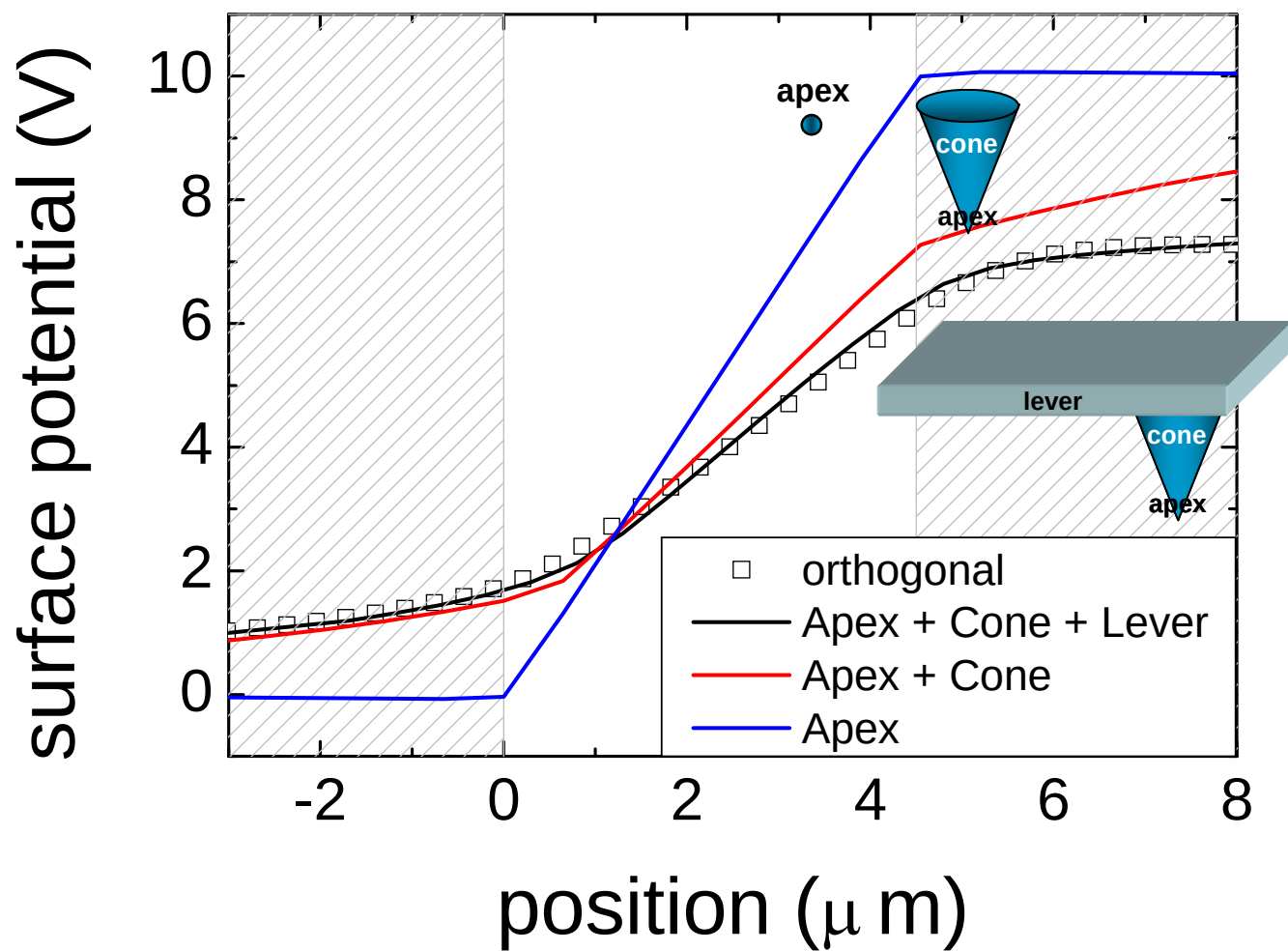
Scattering = meshing limitation



Calculated SKPM Response



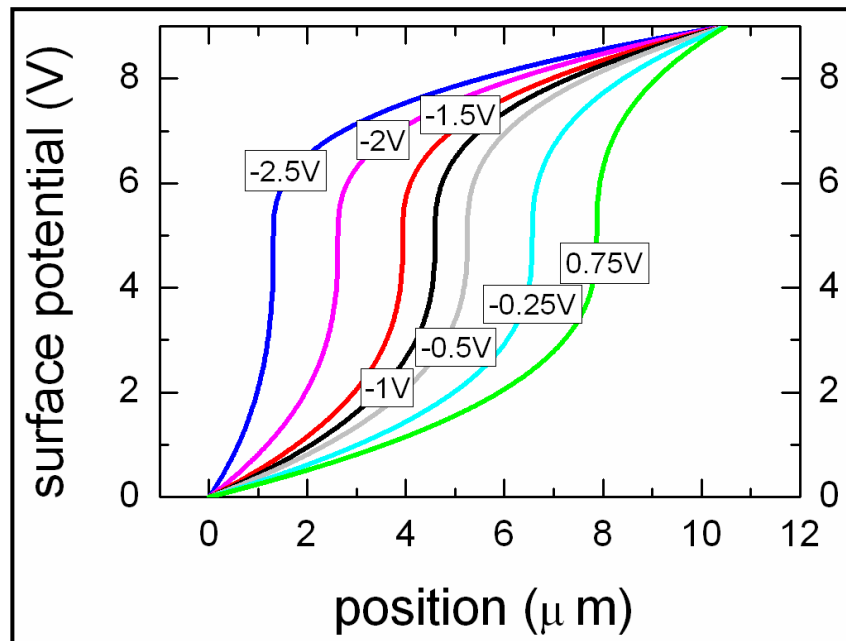
$$\text{Tip} = \text{Apex} + \text{Cone} + \text{Lever}$$



- Apex = perfect probe
- Cone = magnitude + rounding
- Lever = asymmetry

SKPM Response for FET

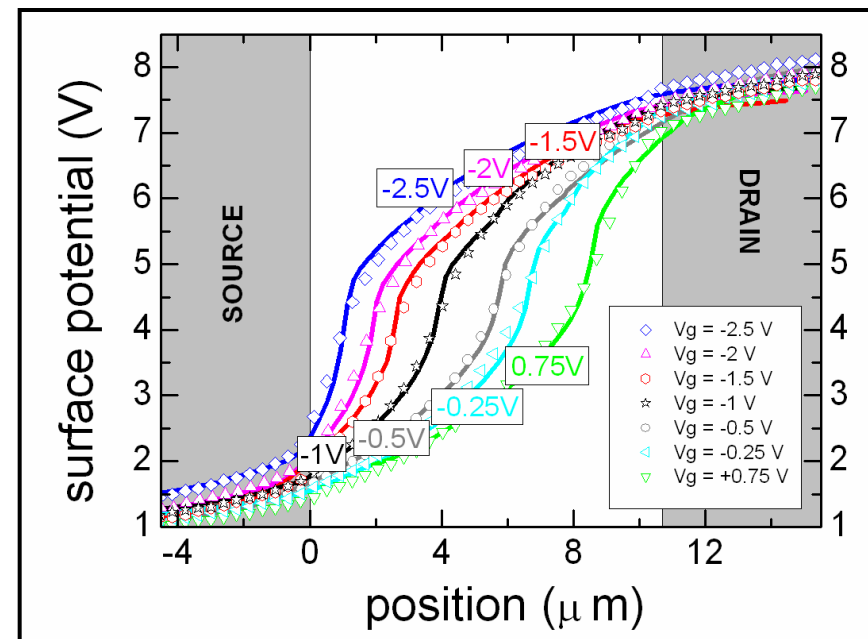
*Theoretical predictions (drift) from Smits
= input of SKPM modeling*



*Assumption:
FWHM = "0" nm*

*Note: We checked that the SKPM probe
influence only few % the source drain current.*

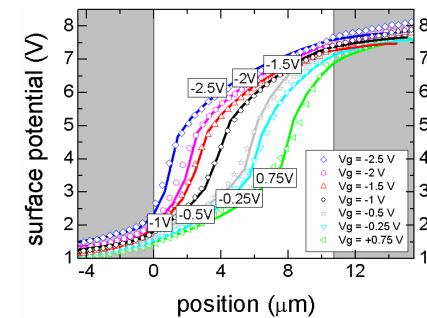
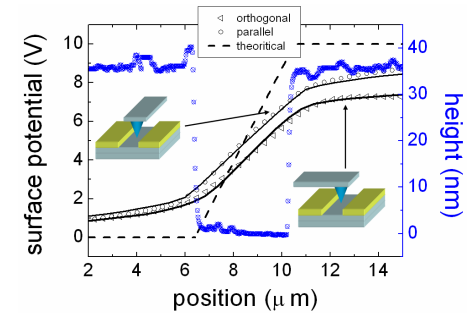
*SKPM
experiments + modeling*



'real' FWHM < 0.5 micron

Conclusions

- Identified the full problem of SKPM response:
 - Developed a numerical model to predict the SKPM response from any theoretical potential.
- FWHM recombination:
 - theoretical (Langevin) ~ 200 nm
 - experimental SKPM response
 - raw ~ 2.1 μm
 - difference with model < 0.5 μm
- SKPM is not optimal for investigating the recombination width.



Thanks to



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